GEM study at Iwate University

Kentaro Negishi (Iwate University)
RD51 collaboration meeting
22-Oct.-2019

Contents

- Motivation
- What is LTCC-GEM
- Experiments
 - Gain & Resolution
 - Stability
 - Uniformity
- Conclusion

Motivation

- Using traditional LCP-GEM, we can not apply high voltage to GEM, in order to be careful for damage due to discharge.
 - → An insulator material with discharge tolerance is desired. In addition, requiring ···
 - Sufficient gain even with a mono-layer
 - Mechanically high strength, rigid structure
 - → for easy handling and gain uniformity
 - Simple production process
 - Cost effective
- Possible candidate is the Low Temperature Co-fired Ceramic

The LTCC-GEM has been originally proposed and developed by Dr. Komiya (Tokyo Metropolitan Industrial Technology Research Institute)

LTCC(Low Temperature Co-fired Ceramic)



- The ceramic is sintered at low temperature ($<1000\,^{\circ}$ C) by adding SiO₂ to Al₂O₃.
- This process allows the co-firing with highly conductive materials such Ag and Au.
- Robust against mechanical and thermal stress.
- Low production costs due to simple process.
- Good thermal conductivity
- The LTCC is used for RF devices and highly integrated circuits.
- The electric parts such as resistor and capacitor can be embedded to the LTCC.

Material	GCS71
Coefficient of thermal expansion [10 ⁻⁶ /K]	5.5
Thermal conductivity [W/m·K]	3.2
Specific heat [J/g·K]	0.66
Young's modulus [GPa]	95
Dielectric constant	7.1
Volume resistivity $[\Omega \cdot cm]$	>1014

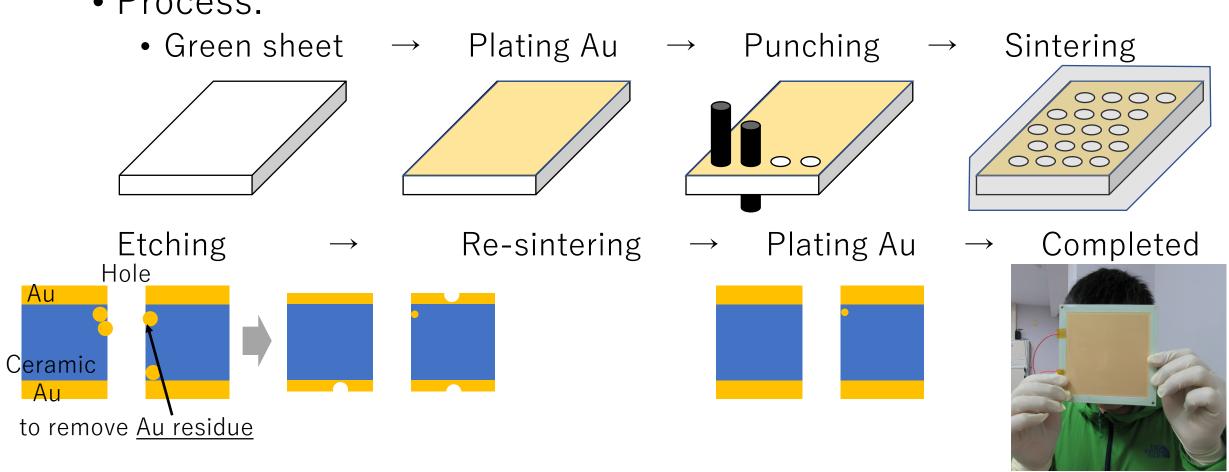
LTCC has no Carbon and is expected to have discharge tolerance.

LTCC-GEM

Hirai Seimitsu Kogyo Corporation, Japan

The material has been developed through collaborative research of Dr. Komiya and Hirai Seimitsu

• Process:



G

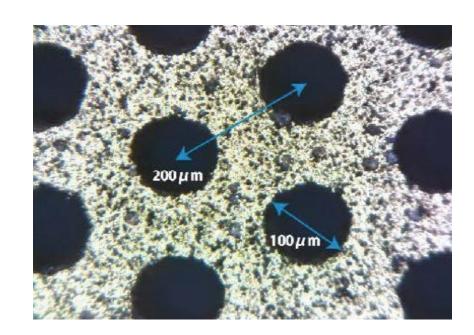
LTCC-GEM @ Iwate-U

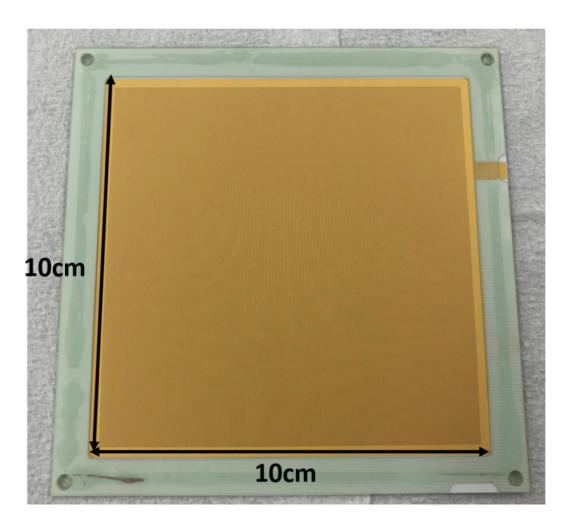
• Effective region 10 cm × 10 cm

• Thickness 200 μ m

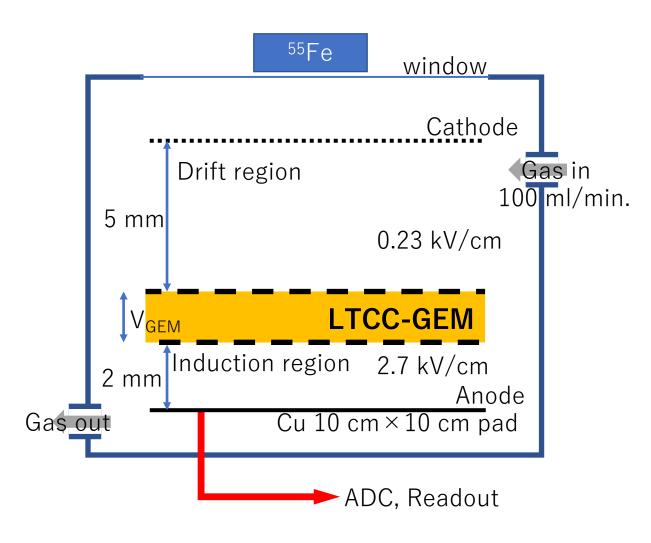
• Hole diameter 100 μ m

• Hole pitch 200 μ m





Experiment



- LTCC-GEM: thickness 200 μ m
- Source: ⁵⁵Fe Xray (5.9 keV)
- Gas:
 - Ar/CO₂ (70% / 30%)
 - T2K=Ar/CF4/iso-C₄H₁₀ (95% / 3% / 2%)
- E-field

(ArCO₂)

(T2K)

- Drift region
 1.5 kV/cm
- 0.23 kV/cm
- Induction region 6 kV/cm

2.7 kV/cm

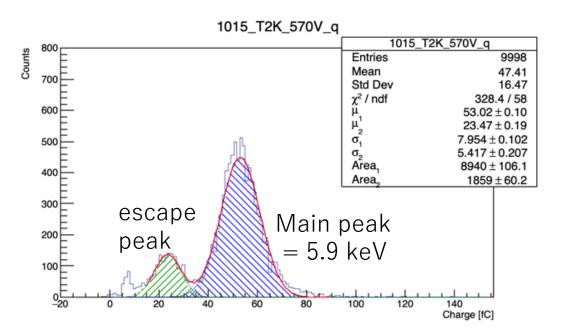
We report

- Gain
- Long term stability
- Uniformity

ate 🥰

Gain, energy resolution and discharge rate

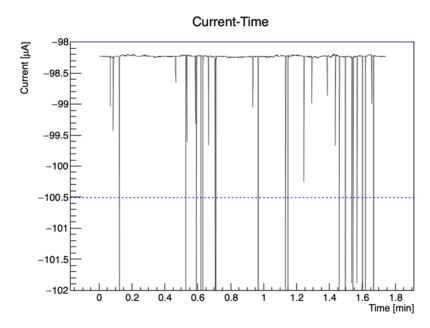
e.g.) 200 μ m thick LTCC-GEM, $V_{GEM} = 565$ V, T2K gas



Assumption of 2 gaussians for main peak and escape peak.

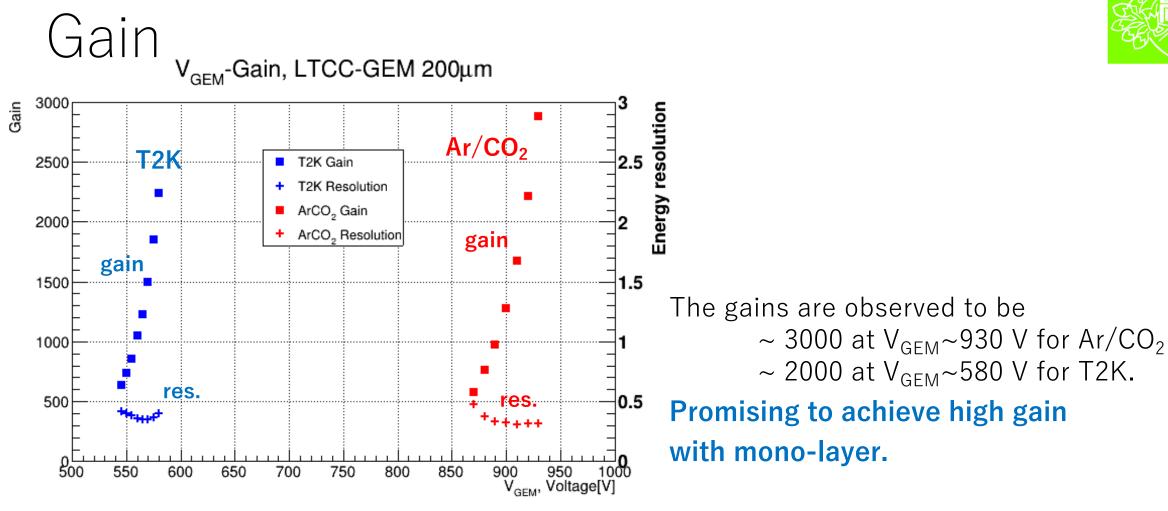
Gain is obtained from mean charge of main peak.

Energy resolution is obtained from HMFW/mean of main peak.



HV current is monitored. We define the discharge as the current falls below I_{thr}.



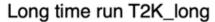


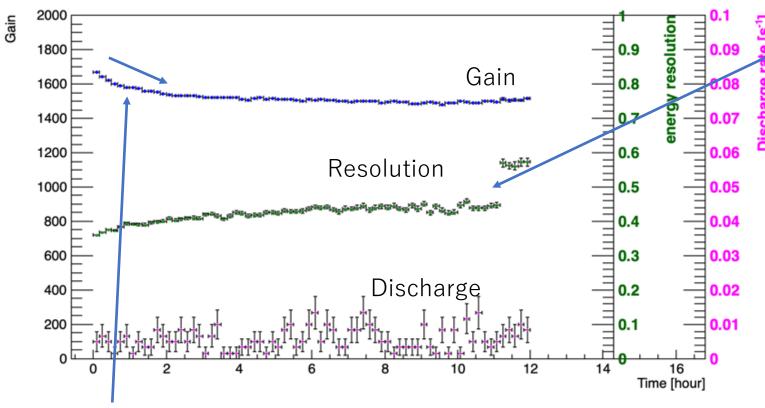
In using T2K gas, energy resolution due to the increase in applied voltage is considered to be affected by discharge.

in using ArCO₂, no significant discharge has occurred yet in this voltage range.

Gain stability

Experiments are performed after enough time(10h) for gas replacement.





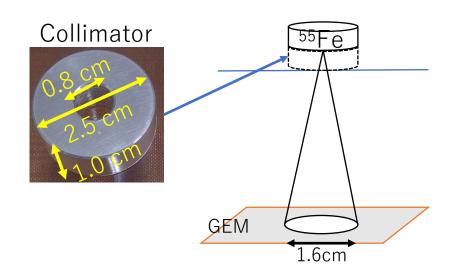
The gain decrease 10 % in $2\sim3$ hours is observed. We think this is due to GEM charging up, and we plan to further study the effects of GEM charge-up.

Resolution changes uncontinuously at 11h after starting, at the same time the gain and discharge rate are not change.

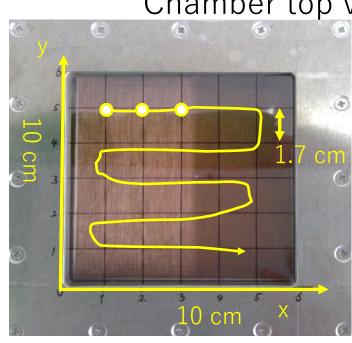
We think that it increased noise from external factors.

To study more further. We has plan to operate more long measurement.

Gain uniformity test



Chamber top view



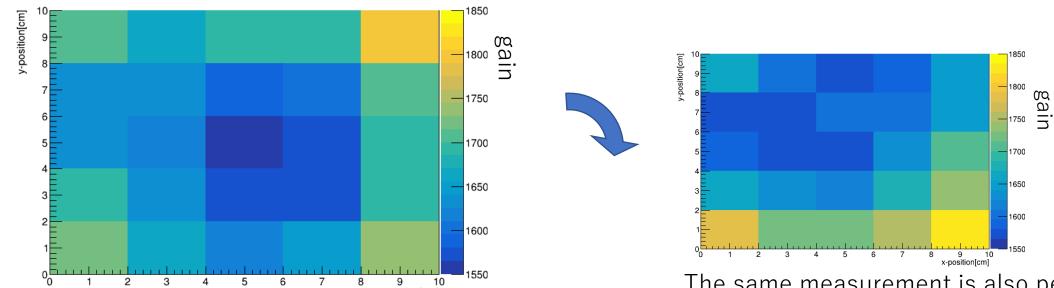
 5×5 measurement points

With 10 cm \times 10 cm LTCC-GEM 200 μ m thick, T2K gas

- Using the collimator, the angle at which the GEM is seen from the source is limited to have a 1.6 cm diameter spread on the GEM.
- Drawing 5×5 lines at window above GEM sensitive area, and gain measurements are performed with placing a ⁵⁵Fe source at each intersection.

Gain uniformity for GEM

Those measurements are performed after gain saturated(>15hours).



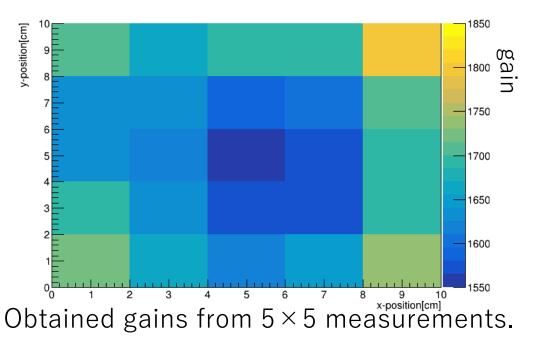
Obtained gains from 5×5 measurements.

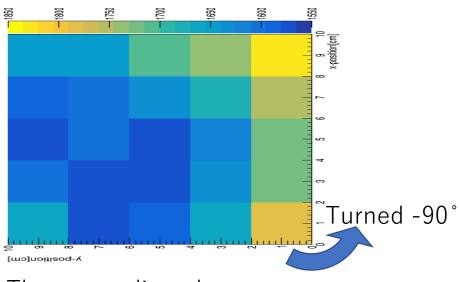
The same measurement is also performed by rotating the GEM 90°.

We also check whether the gain non-uniformity is due to GEM foil itself or other experimental environment.

Gain uniformity for GEM

Those measurements are performed after gain saturated(>15hours).





The same aligned.

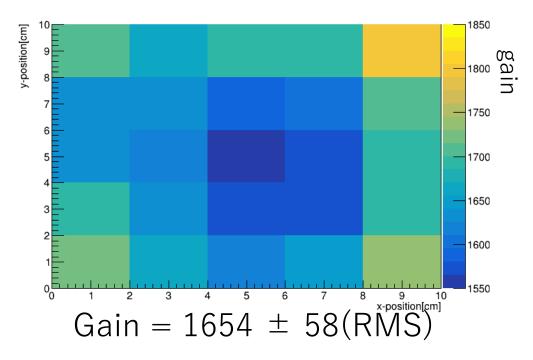
We also check whether the gain non-uniformity is due to GEM foil itself or other experimental environment.

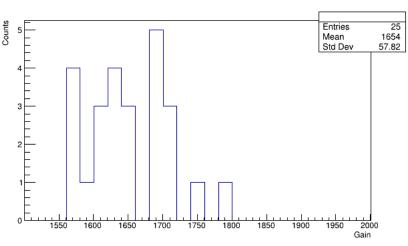
From 2 measurements, almost the same results are obtained.

→ We can obtain the characteristic of the GEM itself.

Gain uniformity for GEM

Those measurements are performed after gain saturated(>15hours).





 5×5 obtained gains distribution.

Our 10 cm \times 10 cm LTCC-GEM(200 μ m thick) gain uniformity is 3.5%. Gains in corner are measured higher.

→ We study further the cause of this non-uniformity.
 e.g) Considering about measurement of GEM thickness, hole diameter, and so on.





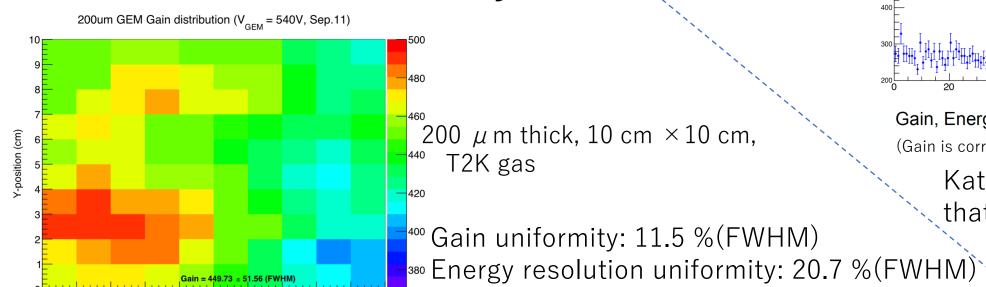
Size 6 cm \times 6 cm, 10 cm \times 10 cm

Thickness 200 μ m, 100 μ m

Hole diag. $100 \mu \text{ m}$ Hole pitch $200 \mu \text{ m}$

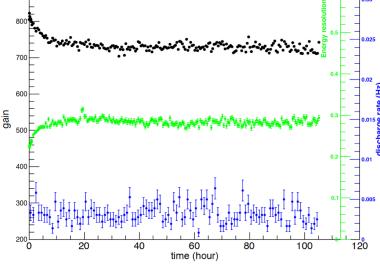
Kato-san has 4 kind of LTCCGEM, and is making 25 cm × 25 cm LTCC-GEM.

Gain uniformity



Logn term stability

200 μ m thick, 6 cm \times 6 cm, T2K gas



Gain, Energy resolution, Discharge rate (Gain is corrected with p/T.)

Kato-san observed that GEM gain decrease (820→730@10h).

Conclusion



- LTCC-GEM is expected to have discharge tolerance.
- Gain > 2000 is archived
 - $V_{GEM} \sim 920V$ with $Ar(70\%)/CO_2(30\%)$ gas
 - $V_{GEM} \sim 580V$ with T2K gas
- Gain long term stability was tested (12 hours). Gain changes about 10 % decrease in 2~3 hours.
 - considering a method to evaluate GEM charge-up.
- Gain uniformity for 10 cm \times 10 cm LTCC-GEM, is estimated to be \sim 3.5 %.
 - considering non-uniformity of thickness of GEM, we are thinking about measurement of GEM thickness.



Backup

LTCC-GEM

@ Iwate U.

• Effective region $10 \text{ cm} \times 10 \text{ cm}$

• Thickness 200 μ m

• Hole diameter 100 μ m

• Hole pitch 200 μ m

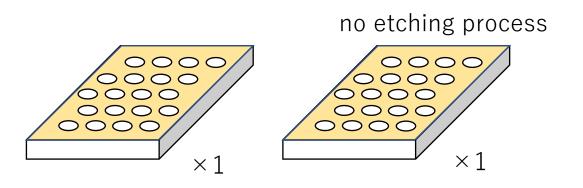
@ Kindai U. (Kato-san)

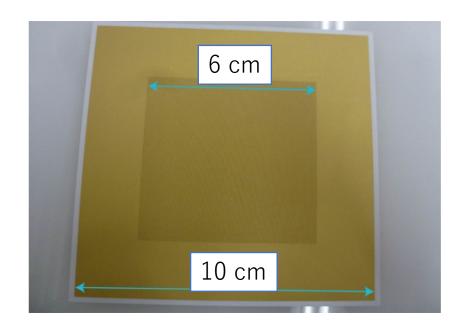
• Effective region 6 cm × 6 cm, 10 cm × 10 cm

• Thickness 200 μ m, 100 μ m

• Hole diameter 100 μ m

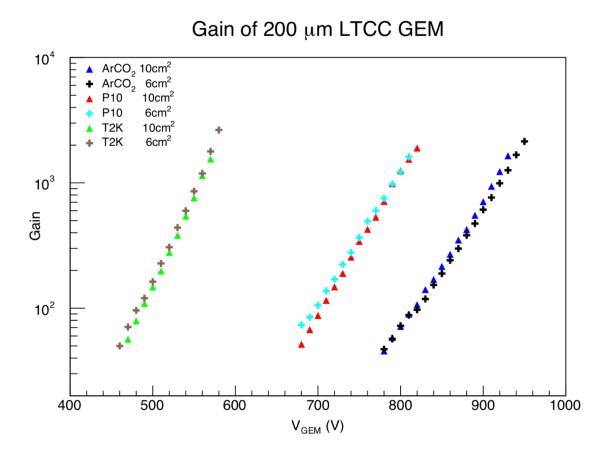
• Hole pitch 200 μ m



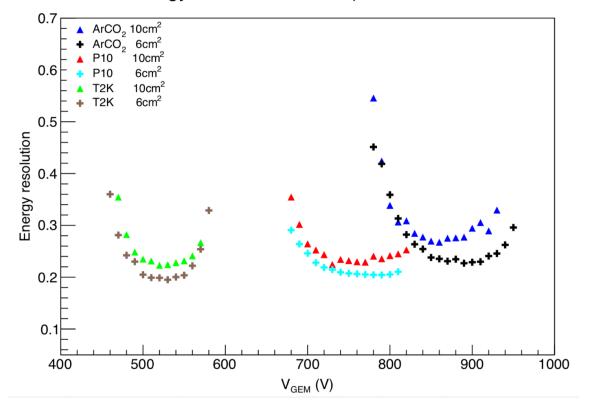


Gain and energy resolution

@ Kindai U.

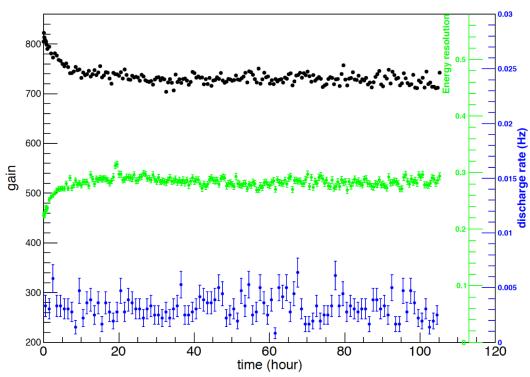


Energy resolution of 200 μm LTCC GEM



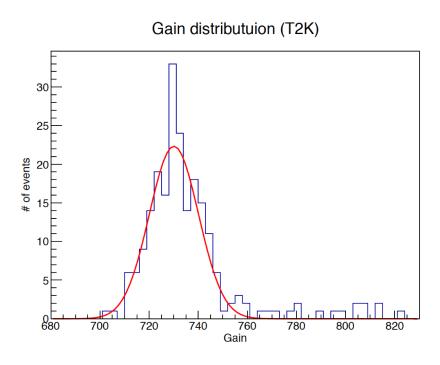
Long term stability





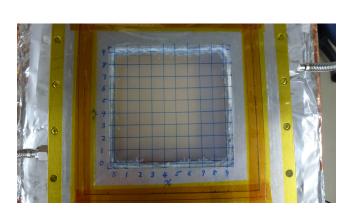
Gain, Energy resolution, 放電率の時間変動

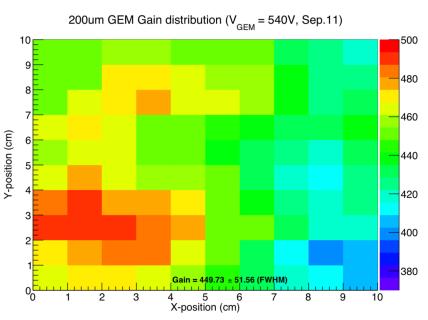
(Gainは温度と圧力の補正済)

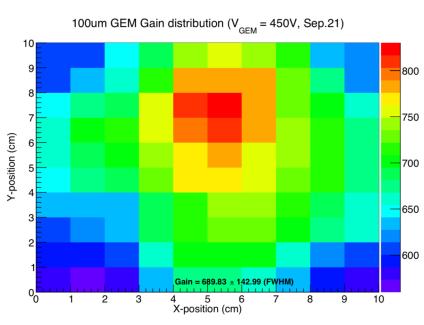


Gain uniformity for GEM @ kindai U.







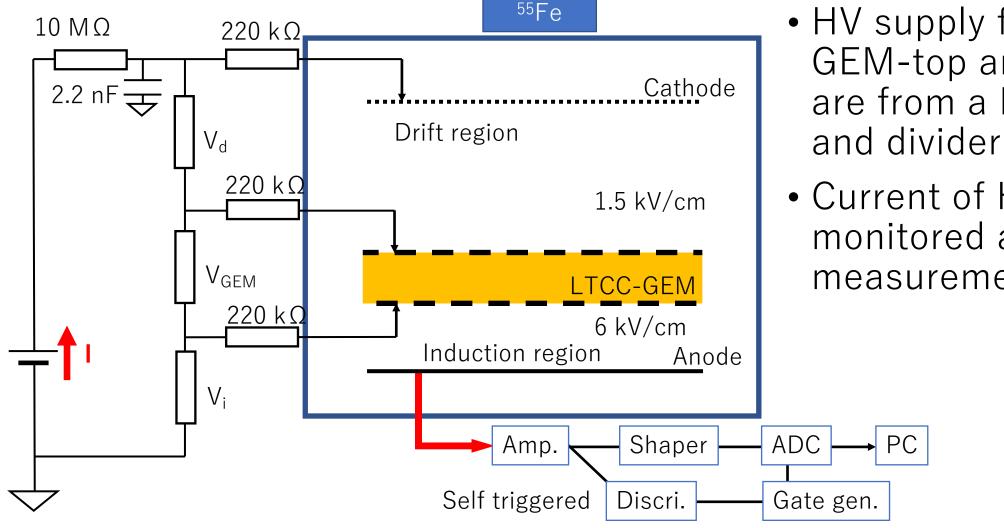


Thickness: 200 μ m Gain = 449.73 \pm 51.56(FWHM) uniformity \sim 4.9 %

Thickness: 100 μ m Gain = 689.83 \pm 142.99(FWHM) uniformity \sim 8.8 %

HV setup

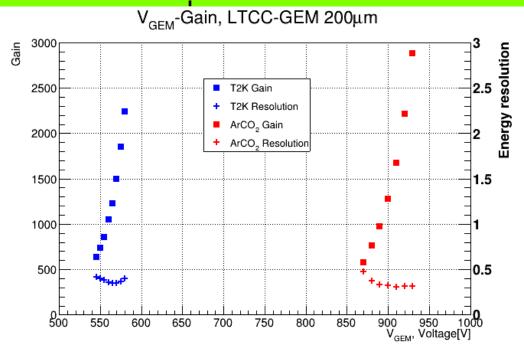


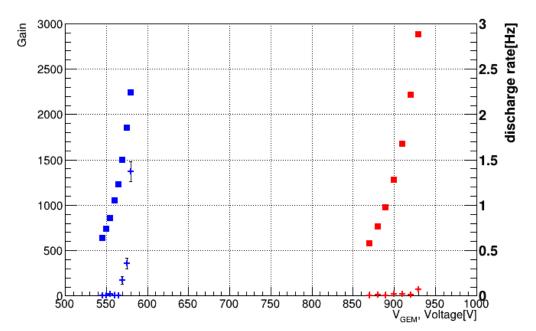


- HV supply for Cathode, GEM-top and bottom are from a HV module and divider.
- Current of HV is monitored at measurements.



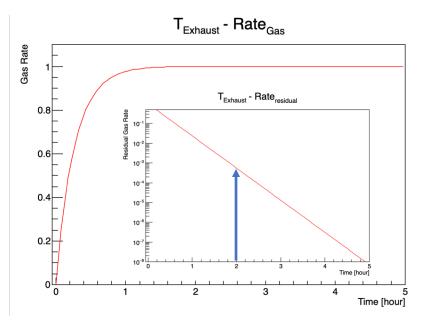


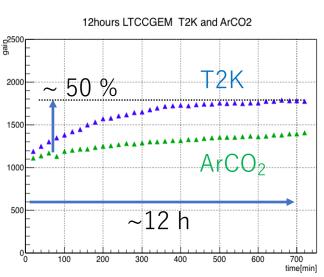


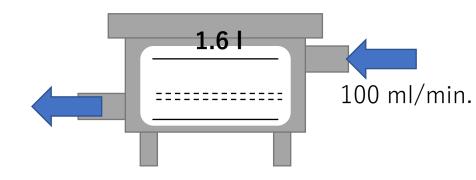


Gas replace

- Chamber (+pipes): 1.6 I
- Gas out is non-return using silicon oil.
- Inner pressure is slightly higher than atmospheric.
- Gas flow rate 100 ml/min.



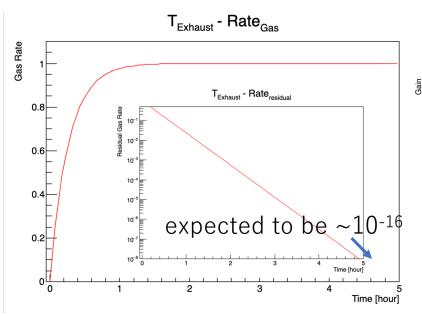


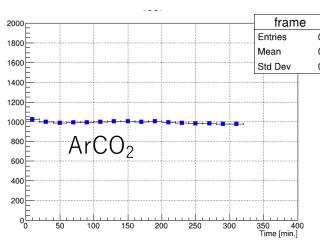


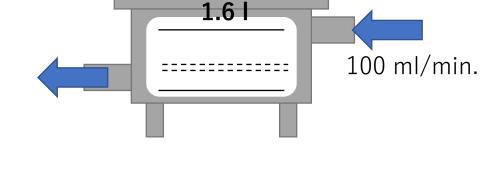
Assuming 0.1 % gas rate is enough, so left gain behavior is observed from measurements which start data taking after 2 hours gas replacement.

Gas replace

- Chamber (+pipes): 1.6 I
- Gas out is non-return using silicon oil.
- Inner pressure is slightly higher than atmospheric.
- Gas flow rate 100 ml/min.







Assuming 0.1 % gas rate is enough, so left gain behavior is observed from measurements which start data taking after 2 hours gas replacement.

However, from another measurement (10h gas replace) we observe that the gain hardly changed.